WHAT IS CLAIMED IS:

- 1 1. A multilayered torsional hinged resonant pivoting device comprising:
- a hinge layer defining a support structure and an attaching member, said support structure
- 3 for pivotally supporting said attaching member along a first axis of rotation by a pair of torsional
- 4 hinges, and said attaching member having a front side and a back side;
- a front layer having a functional surface portion, and a back portion, said back portion of
- 6 said front layer mounted to said front side of said attaching member and said front layer having a
- 7 known mass moment about said first axis; and
- a back layer mounted on said back side of said attaching member and having a mass
- 9 moment substantially equal to and opposite said known mass moment of said front layer, such
- that the center of mass of the combined front and back layers is substantially coplanar with the
- first axis of rotation and the moment of inertia of said multilayered torsional hinged device is
- substantially centered on said first axis of rotation.
 - 1 2. The multilayered device of claim 1 wherein said hinge layer comprises an anchor
- 2 member connected to said attaching member along said first axis by said first pair of torsional
- 3 hinges.
- 1 3. The multilayered device of claim 2 wherein said anchor member is a support frame.
- 1 4. The multilayered device of claim 2 wherein said anchor member is a pair of anchor pads.
- 1 5. The multilayered device of claim 1 wherein said support structure of said hinge layer
- 2 comprises a gimbals portion connected to said attaching member along said first axis by said pair

- 3 of torsional hinges and an anchor member pivotally supporting said gimbals portion by a second
- 4 pair of torsional hinges along a second axis substantially orthogonal to said first axis.
- 1 6. The multilayered device of claim 5 wherein said anchor member is a support frame.
- 1 7. The multilayered device of claim 5 wherein said anchor member is a pair of anchor pads.
- 1 8. The multilayered device of claim 1 wherein said back layer is a permanent magnet.
- 1 9. The multilayered device of claim 8 and further comprising a magnetic coil connected to
- 2 an alternating voltage having a frequency substantially equal to a selected sweep frequency of
- 3 said pivoting device and wherein said magnetic coil and said permanent magnet interact to create
- 4 pivotal movement of said functional surface at said resonant frequency.
- 1 10. The multilayered device of claim 9 wherein said selected sweep frequency is
- 2 substantially equal, to the resonant pivoting frequency of said device about said first axis.
- 1 11. The multilayered device of claim 1 wherein said back layer has a size and shape
- 2 substantially matching said size and shape of said attaching member.
- 1 12. The multilayered device of claim 11 and further comprising piezoelectric material
- 2 bonded to said support structure of said hinge layer to create resonant pivoting of said device.
- 1 13. The multilayered device of claim 1 wherein said hinge layer is made from single crystal
- 2 silicon.
- 1 14. The multilayered device of claim 13 wherein said front layer is made from single crystal
- 2 silicon.

- 1 15. The multilayered device of claim 5 wherein said back layer is a permanent magnet.
- 1 16. The multilayered device of claim 15 and further comprising a magnetic coil connected to
- 2 an alternating voltage having a frequency equal to a selected sweep frequency of said pivoting
- 3 device and wherein said magnetic coil and said permanent magnet interact to create pivotal
- 4 oscillations of said device at said selected sweep frequency.
- 1 17. The multilayered device of claim 16 wherein said selected sweep frequency is
- 2 substantially equal, to the resonant pivoting frequency of said device.
- 1 18. The multilayered device of claim 5 wherein said back layer has a size and shape
- 2 substantially matching said size and shape of said attaching member.
- 1 19. The multilayered device of claim 18 and further comprising piezoelectric material
- 2 bonded to said support structure of said hinge layer to create resonant pivoting of said device
- 3 about said first axis.
- 1 20. The multilayered device of claim 5 wherein said hinge layer is made from single crystal
- 2 silicon.
- 1 21. The multilayered device of claim 20 wherein said front layer is made from single crystal
- 2 silicon.
- 1 22. The multilayered device of claim 1 wherein said functional surface of said front layer is a
- 2 mirror.
- 1 23. The multilayered device of claim 22 wherein said back layer is a permanent magnet.

- 1 24. The multilayered device of claim 23 and further comprising a magnetic coil connected to
- 2 an alternating voltage having a frequency equal to a selected sweep frequency of said mirror
- 3 functional surface and wherein said magnetic coil and said permanent magnet interact to create
- 4 pivotal oscillations of said mirror at said selected sweep frequency.
- 1 25. The multilayered device of claim 24 wherein said selected sweep frequency is
- 2 substantially equal to the resonant frequency of said mirror functional surface about said first
- 3 axis.
- 1 26. The multilayered device of claim 25 used as a drive engine to provide a scanning beam.
- 1 27. The multilayered device of claim 26 wherein said drive engine provides the scanning
- 2 beam for a printer.
- 1 28. The multilayered device of claim 22 wherein said back layer has a size and shape
- 2 substantially matching said size and shape of said attaching member.
- 1 29. The multilayered device of claim 28 and further comprising piezoelectric material
- 2 bonded to said support structure of said hinge layer to create resonant pivoting of said device.
- 1 30. The multilayered device of claim 29 used as the drive engine to provide a scanning beam.
- 1 31. The multilayered device of claim 5 wherein said functional surface of said front layer is a
- 2 mirror.
- 1 32. The multilayered device of claim 31 and further comprising a magnetic coil connected to
- 2 an alternating voltage having a frequency equal to a selected sweep frequency of said pivoting

- 3 device and wherein said magnetic coil and said permanent magnet interact to create pivotal
- 4 oscillations of said device at said selected sweep frequency.
- 1 33. The multilayered device of claim 32 wherein said selected sweep frequency is
- 2 substantially equal, to the resonant pivoting frequency of said device.
- 1 34. The multilayered device of claim 31 wherein said back layer has a size and shape
- 2 substantially matching said size and shape of said attaching member.
- 1 35. The multilayered device of claim 34 and further comprising piezoelectric material
- 2 bonded to said support structure of said hinge layer to create resonant pivoting of said device
- 3 about said first axis.
- 1 36. The multilayered device of claim 31 wherein said hinge layer is made from single crystal
- 2 silicon.
- 1 37. The multilayered device of claim 36 wherein said front layer is made from single crystal
- 2 silicon.